

SCDS189F - JANUARY 2005 - REVISED MAY 2013

# 10-Ω QUAD SPDT ANALOG SWITCH

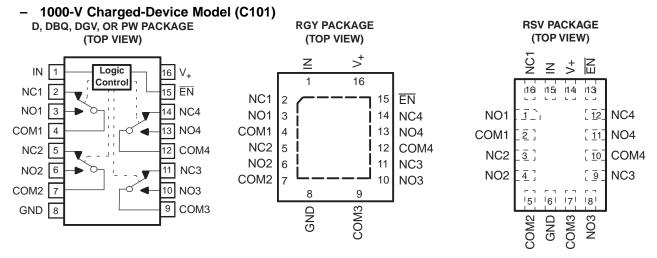
Check for Samples: TS3A5018

## FEATURES

- Low ON-State Resistance (10 Ω)
- Low Charge Injection
- Excellent ON-State Resistance Matching
- Low Total Harmonic Distortion (THD)
- 1.8-V to 3.6-V Single-Supply Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)

## APPLICATIONS

- Sample-and-Hold Circuits
- Battery-Powered Equipment
- Audio and Video Signal Routing
- Communication Circuits



#### DESCRIPTION

The TS3A5018 is a quad single-pole double-throw (SPDT) analog switch that is designed to operate from 1.8 V to 3.6 V. This device can handle both digital and analog signals, and signals up to  $V_+$  can be transmitted in either direction.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

# TS3A5018

#### SCDS189F-JANUARY 2005-REVISED MAY 2013

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ORDERING INFORMATION <sup>(1)</sup>								
T <sub>A</sub>	PACKAG	E <sup>(2)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING				
	SOIC – D	Tube of 40	TS3A5018D	T0245040				
	50IC - D	Reel of 2500	TS3A5018DR	- TS3A5018				
	SSOP (QSOP) – DBQ	Reel of 2500	TS3A5018DBQR	YA018				
		Tube of 90	TS3A5018PW	XA040				
–40°C to 85°C	TSSOP – PW	Reel of 2000	TS3A5018PWR	- YA018				
	TVSOP – DGV	Reel of 2000	TS3A5018DGVR	YA018				
		Deal at 0000	TS3A5018RGYR	X4040				
	QFN – RGY	Reel of 3000	TS3A5018RGYRG4	- YA018				
	uQFN – RSV	Reel of 3000	TS3A5018RSVR	ZUN				

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

Configuration	Quad Single-Pole, Double Throw (4 × SPDT)				
Number of channels	4				
ON-state resistance (ron)	7 Ω				
ON-state resistance match ( $\Delta r_{on}$ )	0.3 Ω				
ON-state resistance flatness (ron(flat))	5 Ω				
Turn-on/turn-off time (t <sub>ON</sub> /t <sub>OFF</sub> )	3.5 ns/2 ns				
Charge injection (Q <sub>C</sub> )	2 pC				
Bandwidth (BW)	300 MHz				
OFF isolation (O <sub>ISO</sub> )	–48 dB at 10 MHz				
Crosstalk (X <sub>TALK</sub> )	–48 dB at 10 MHz				
Total harmonic distortion (THD)	0.2%				
Leakage current (I <sub>COM(OFF)</sub>	±5 μΑ				
Power-supply current (I <sub>+</sub> )	2.5 µA				
Package options	16-pin QFN, uQFN, SOIC, SSOP, TSSOP, or TVSOF				

## SUMMARY OF CHARACTERISTICS<sup>(1)</sup>

(1)  $V_{+} = 1.65 \text{ V} \sim 1.95 \text{ V}, T_{A} = 25^{\circ}\text{C}$ 

## FUNCTION TABLE

EN	IN	NO TO COM, COM TO NO	NC TO COM, COM TO NC
L	L	OFF	ON
L	н	ON	OFF
н	х	OFF	OFF



SCDS189F - JANUARY 2005 - REVISED MAY 2013

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## Absolute Minimum and Maximum Ratings<sup>(1)</sup> <sup>(2)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V+	Supply voltage range <sup>(3)</sup>		-0.5	4.6	V
V <sub>NC</sub> V <sub>NO</sub> V <sub>COM</sub>	Analog voltage range <sup>(3) (4)</sup>		-0.5	4.6	V
IK	Analog port diode current	$V_{NC}, V_{NO}, V_{COM} < 0$	-50		mA
I <sub>NC</sub> I <sub>NO</sub> I <sub>COM</sub>	On-state switch current	$V_{NC}$ , $V_{NO}$ , $V_{COM}$ = 0 to 7 V	-64	64	mA
VI	Digital input voltage range <sup>(3) (4)</sup>	I	-0.5	4.6	V
I <sub>IK</sub>	Digital input clamp current	V <sub>1</sub> < 0	-50		mA
l+	Continuous current through V+		-100	100	mA
I <sub>GND</sub>	Continuous current through GND		-100	100	mA
		D package		73	
		DBQ package		90	
~	Declares the recelling a decree (5)	DGV package		120	0000
$\theta_{JA}$	JA Package thermal impedance <sup>(5)</sup>	PW package		108	°C/W
		RGY package		51	
		RSV package		184	
T <sub>stg</sub>	Storage temperature range		65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating" conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum (2)

(3) All voltages are with respect to ground, unless otherwise specified.

(0) (4) (5) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

The package thermal impedance is calculated in accordance with JESD 51-7.

SCDS189F-JANUARY 2005-REVISED MAY 2013

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## Electrical Characteristics for 3.3-V Supply<sup>(1)</sup>

 $V_{+} = 3 \text{ V}$  to 3.6 V,  $T_{A} = -40^{\circ}\text{C}$  to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CON	DITIONS	T <sub>A</sub>	۷.	MIN	TYP	MAX	UNIT
Analog Switch						-			
Analog signal range	V <sub>COM</sub> , V <sub>NO</sub> , V <sub>NC</sub>					0		V+	V
ON-state resistance	r <sub>on</sub>	$\begin{array}{l} 0 \leq (V_{NC} \text{ or } V_{NO}) \leq V_{+}, \\ I_{COM} = -32 \ mA, \end{array}$	Switch ON, See Figure 19	25°C Full	3 V		7	10 12	Ω
ON-state				25°C			0.3	0.8	
resistance match between channels	$\Delta r_{on}$	$V_{NC}$ or $V_{NO} = 2.1$ V, $I_{COM} = -32$ mA,	Switch ON, See Figure 19	Full	3 V			1	Ω
ON-state		$0 \le (V_{NC} \text{ or } V_{NO}) \le V_+,$	Switch ON,	25°C			5	7	_
resistance flatness	r <sub>on(flat)</sub>	$I_{COM} = -32 \text{ mA},$	See Figure 19	Full	3 V			8	Ω
		$V_{NC}$ or $V_{NO} = 1 V$ , $V_{COM} = 3 V$ ,		25°C		-0.1	0.05	0.1	
NC, NO	I <sub>NC(OFF)</sub> ,	$v_{COM} = 3 V$ , or $V_{NC}$ or $V_{NO} = 3 V$ , $V_{COM} = 1 V$ ,	Switch OFF, See Figure 20	Full	3.6 V	-0.2		0.2	
OFF leakage current	I <sub>NO(OFF)</sub>	$V_{NC}$ or $V_{NO} = 0$ to 3.6 V,		25°C		-2	0.05	2	- μΑ
			Switch OFF, See Figure 20	Full	0 V	-10		10	
		$V_{COM} = 1 V,$		25°C		-0.1	0.05	0.1	
COM		$ \begin{array}{l} V_{NC} \text{ or } V_{NO} = 3 \text{ V}, \\ \text{or} \\ V_{COM} = 3 \text{ V}, \\ V_{NC} \text{ or } V_{NO} = 3 \text{ V}, \end{array} $	Switch OFF, See Figure 20	Full	3.6 V	-0.2		0.2	
OFF leakage current	I <sub>COM(OFF)</sub>	$V_{COM} = 0$ to 3.6 V,		25°C		-2	0.05	2	μA
			Switch OFF, See Figure 20	Full	0 V	-10		10	
		$V_{NC}$ or $V_{NO} = 1 V$ ,		25°C		-0.1	0.05	0.1	
NC, NO ON leakage current	I <sub>NC(ON)</sub> , I <sub>NO(ON)</sub>	$\label{eq:VCOM} \begin{array}{l} V_{COM} = Open, \\ or \\ V_{NC} \mbox{ or } V_{NO} = 3 \mbox{ V}, \\ V_{COM} = Open, \end{array}$	Switch ON, See Figure 21	Full	3.6 V	-0.2		0.2	μA
		$V_{COM} = 1 V,$		25°C		-0.1	0.05	0.1	
COM ON leakage current	I <sub>COM(ON)</sub>	$ \begin{array}{l} V_{NC} \mbox{ or } V_{NO} = \mbox{ Open,} \\ \mbox{ or } \\ V_{COM} = 3 \ V, \\ V_{NC} \mbox{ or } V_{NO} = \mbox{ Open,} \end{array} $	Switch ON, See Figure 21	Full	3.6 V	-0.2		0.2	μA
Digital Control	nputs (IN, EN)	(2)							
Input logic high	V <sub>IH</sub>			Full		2		V <sub>+</sub>	V
Input logic low	V <sub>IL</sub>			Full		0		0.8	V
Input leakage current	$I_{\rm IH},I_{\rm IL}$	$V_{I} = V_{+} \text{ or } 0$		25°C Full	3.6 V	-1 -1	0.05	1	μA

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

 (2) All unused digital inputs of the device must be held at V<sub>+</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



#### SCDS189F-JANUARY 2005-REVISED MAY 2013

## Electrical Characteristics for 3.3-V Supply<sup>(1)</sup> (continued)

 $V_{+} = 3 V$  to 3.6 V,  $T_{A} = -40^{\circ}C$  to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CON	DITIONS	T <sub>A</sub>	٧,	MIN	TYP	MAX	UNIT
Dynamic									
		N 2N	0 25 pF	25°C	3.3 V	2.5	3.5	8	
Turn-on time	t <sub>ON</sub>	$V_{COM} = 2 V,$ R <sub>L</sub> = 300 Ω,	C <sub>L</sub> = 35 pF, See Figure 23	Full	3 V to 3.6 V	2.5		9	ns
		$V_{COM} = 2 V$ ,	C <sub>L</sub> = 35 pF,	25°C	3.3 V	0.5	2	6.5	
Turn-off time	t <sub>OFF</sub>	$V_{COM} = 2 V,$ $R_{L} = 300 \Omega,$	See Figure 23	Full	3 V to 3.6 V	0.5		7	ns
Charge injection	Q <sub>C</sub>	$V_{GEN} = 0,$ $R_{GEN} = 0,$	C <sub>L</sub> = 0.1 nF, See Figure 28	25°C	3.3 V		2		рС
NC, NO OFF capacitance	$\begin{array}{c} C_{NC(OFF)},\\ C_{NO(OFF)} \end{array}$	$V_{NC}$ or $V_{NO} = V_{+}$ or GND, Switch OFF,	See Figure 22	25°C	3.3 V		4.5		pF
COM OFF capacitance	C <sub>COM(OFF)</sub>	$V_{COM} = V_+ \text{ or GND},$ Switch OFF,	See Figure 22	25°C	3.3 V		9		pF
NC, NO ON capacitance	C <sub>NC(ON)</sub> , C <sub>NO(ON)</sub>	$V_{NC}$ or $V_{NO} = V_{+}$ or GND, Switch ON,	See Figure 22	25°C	3.3 V		16		pF
COM ON capacitance	C <sub>COM(ON)</sub>	$V_{COM} = V_{+}$ or GND, Switch ON,	See Figure 22	25°C	3.3 V		16		pF
Digital input capacitance	CI	$V_I = V_+ \text{ or } GND,$	See Figure 22	25°C	3.3 V		3		pF
Bandwidth	BW	$R_{L} = 50 \Omega$ , Switch ON,	See Figure 24	25°C	3.3 V		300		MHz
OFF isolation	O <sub>ISO</sub>		Switch OFF, See Figure 25	25°C	3.3 V		-48		dB
Crosstalk	X <sub>TALK</sub>		Switch ON, See Figure 26	25°C	3.3 V		-48		dB
Crosstalk adjacent	X <sub>TALK(ADJ)</sub>	$ \begin{array}{l} R_{L} = 50 \ \Omega, \\ f = 10 \ MHz, \end{array} $	Switch ON, See Figure 27	25°C	3.3 V		81		dB
Total harmonic distortion	THD	$ \begin{array}{l} R_L = 600 \ \Omega, \\ C_L = 50 \ pF, \end{array} $	f = 20 Hz to 20 kHz, See Figure 29	25°C	3.3 V		0.21		%
Supply				·					
Positive supply	I	$V_1 = V_+$ or GND,	Switch ON or OFF	25°C	3.6 V		2.5	7	μA
current	I+	$v_{\parallel} = v_{+} \cup I \cup U \cup U,$		Full	3.0 V			10	μΑ

SCDS189F-JANUARY 2005-REVISED MAY 2013

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## Electrical Characteristics for 2.5-V Supply<sup>(1)</sup>

 $V_{+}$  = 2.3 V to 2.7 V,  $T_{A}$  = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CO	NDITIONS	TA	٧.	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V <sub>COM</sub> , V <sub>NC</sub> , V <sub>NO</sub>					0		V+	V
ON-state resistance	r <sub>on</sub>	$\begin{array}{l} 0 \leq (V_{NC} \text{ or } V_{NO}) \leq V_{+}, \\ I_{COM} = -24 \text{ mA}, \end{array}$	Switch ON, See Figure 19	25°C Full	2.3 V		12	20 22	Ω
ON-state resistance match between channels	Δr <sub>on</sub>	$V_{NC}$ or $V_{NO}$ = 1.6 V, I <sub>COM</sub> = -24 mA,	Switch ON, See Figure 19	25°C Full	2.3 V		0.3	1	Ω
ON-state resistance flatness	r <sub>on(flat)</sub>	$\begin{array}{l} 0 \leq (V_{NC} \text{ or } V_{NO}) \leq V_{+}, \\ I_{COM} = -24 \text{ mA}, \end{array}$	Switch ON, See Figure 19	25°C Full	2.3 V		14	18 20	Ω
		$V_{NC}$ or $V_{NO} = 0.5 V$ ,		25°C		-0.1	0.05	0.1	
NC, NO	I <sub>NC(OFF)</sub> ,	$\label{eq:comparameters} \begin{array}{l} V_{COM} = 2.2 \ V, \\ \text{or} \\ V_{NC} \ \text{or} \ V_{NO} = 2.2 \ V, \\ V_{COM} = 0.5 \ V, \end{array}$	Switch OFF, See Figure 20	Full	2.7 V	-0.2		0.2	
OFF leakage current	I <sub>NO(OFF)</sub>	$V_{NC}$ or $V_{NO} = 0$ to 3.6 V,		25°C		-2	0.05	2	- μΑ
			Switch OFF, See Figure 20	Full	0 V	-10		10	
		V <sub>COM</sub> = 0.5 V,		25°C		-0.1	0.05	0.1	
COM	$V_{NC} \text{ or } V_{NO} = 2.2 \text{ V}, \qquad \text{Switch OFF,} \\ \text{or} \qquad V_{COM} = 2.2 \text{ V}, \qquad \text{See Figure 20} \\ V_{NC} \text{ or } V_{NO} = 0.5 \text{ V}, \qquad \text{See Figure 20} \\ Substituting the set of the set of$	Full	2.7 V	-0.2		0.2			
OFF leakage current	I <sub>COM(OFF)</sub>	$V_{COM} = 0$ to 3.6 V,		25°C		-2	0.05	2	μA
			Switch OFF, See Figure 20	Full	0 V	-10		10	
		$V_{NC}$ or $V_{NO} = 0.5 V$ ,		25°C		-0.1	0.05	0.1	
NC, NO ON leakage current	I <sub>NC(ON)</sub> , I <sub>NO(ON)</sub>	$\label{eq:VCOM} \begin{array}{l} V_{COM} = Open, \\ or \\ V_{NC} \mbox{ or } V_{NO} = 2.2 \mbox{ V}, \\ V_{COM} = Open, \end{array}$	Switch ON, See Figure 21	Full	2.7 V	-0.2		0.2	μA
		V <sub>COM</sub> = 0.5 V,		25°C		-0.1	0.05	0.1	
COM ON leakage current	I <sub>COM(ON)</sub>	$ \begin{array}{l} V_{NC} \mbox{ or } V_{NO} = \mbox{ Open}, \\ \mbox{ or } \\ V_{COM} = 2.2 \ V, \\ V_{NC} \mbox{ or } V_{NO} = \mbox{ Open}, \end{array} $	Switch ON, See Figure 21	Full	2.7 V	-0.2		0.2	μA
Digital Control I	nputs (IN, EN) <sup>(</sup>	2)							
Input logic high	V <sub>IH</sub>			Full		1.7		V <sub>+</sub>	V
Input logic low	V <sub>IL</sub>			Full		0		0.7	V
Input leakage current	I <sub>IH</sub> , I <sub>IL</sub>	$V_{I} = V_{+}$ or 0		25°C Full	2.7 V	-0.1 -1	0.05	0.1 1	μA

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

 (2) All unused digital inputs of the device must be held at V<sub>+</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



#### SCDS189F-JANUARY 2005-REVISED MAY 2013

## Electrical Characteristics for 2.5-V Supply<sup>(1)</sup> (continued)

 $V_{+} = 2.3 \text{ V}$  to 2.7 V,  $T_{A} = -40^{\circ}\text{C}$  to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CON	IDITIONS	TA	٧,	MIN	TYP	MAX	UNIT
Dynamic									
		V 4 E V	0 25 pF	25°C	2.5 V	2.5	5	9.5	
Turn-on time	t <sub>ON</sub>	$V_{COM} = 1.5 \text{ V},$ R <sub>L</sub> = 300 Ω,	C <sub>L</sub> = 35 pF, See Figure 23	Full	2.3 V to 2.7 V	2.5		10.5	ns
		V <sub>COM</sub> = 1.5 V,	$C_{1} = 35  \text{pF},$	25°C	2.5 V	0.5	3	7.5	
Turn-off time	t <sub>OFF</sub>	$R_{L} = 300 \Omega,$	See Figure 23	Full	2.3 V to 2.7 V	0.5		9	ns
Charge injection	Q <sub>C</sub>	$V_{GEN} = 0,$ $R_{GEN} = 0,$	C <sub>L</sub> = 0.1 nF, See Figure 28	25°C	2.5 V		1		рС
NC, NO OFF capacitance	$\begin{array}{c} C_{NC(OFF)},\\ C_{NO(OFF)} \end{array}$	$V_{NC}$ or $V_{NO} = V_{+}$ or GND, Switch OFF,	See Figure 22	25°C	2.5 V		3		pF
COM OFF capacitance	C <sub>COM(OFF)</sub>	$V_{COM} = V_+ \text{ or GND},$ Switch OFF,	See Figure 22	25°C	2.5 V		9		pF
NC, NO ON capacitance	C <sub>NC(ON)</sub> , C <sub>NO(ON)</sub>	$V_{NC}$ or $V_{NO} = V_{+}$ or GND, Switch ON,	See Figure 22	25°C	2.5 V		16		pF
COM ON capacitance	C <sub>COM(ON)</sub>	V <sub>COM</sub> = V <sub>+</sub> or GND, Switch ON,	See Figure 22	25°C	2.5 V		16		pF
Digital input capacitance	CI	$V_1 = V_+ \text{ or } GND,$	See Figure 22	25°C	2.5 V		3		pF
Bandwidth	BW	$R_L = 50 \Omega$ , Switch ON,	See Figure 24	25°C	2.5 V		300		MHz
OFF isolation	O <sub>ISO</sub>	$ \begin{array}{l} R_{L} = 50 \ \Omega, \\ f = 10 \ MHz, \end{array} $	Switch OFF, See Figure 25	25°C	2.5 V		-48		dB
Crosstalk	X <sub>TALK</sub>	$ \begin{array}{l} R_{L} = 50 \ \Omega, \\ f = 10 \ MHz, \end{array} $	Switch ON, See <mark>Figure 26</mark>	25°C	2.5 V		-48		dB
Crosstalk adjacent	X <sub>TALK(ADJ)</sub>	$ \begin{array}{l} R_{L} = 50 \ \Omega, \\ f = 10 \ MHz, \end{array} $	Switch ON, See Figure 27	25°C	3.3 V		81		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 50 pF,$	f = 20 Hz to 20 kHz, See Figure 29	25°C	2.5 V		0.33		%
Supply				<u> </u>	· · · · · ·				
Positive supply current	I+	$V_1 = V_+$ or GND,	Switch ON or OFF	25°C Full	2.7 V		2.5	7 10	μA

# Electrical Characteristics for 2.1-V Supply <sup>(1)</sup>

 $V_{+}$  = 2.00 V to 2.20 V,  $T_{A}$  = -40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T <sub>A</sub>	٧,	MIN	ΤΥΡ ΜΑΧ	UNIT
Digital Control	Inputs (IN1-2,IN3	-4)					
Input logic high	V <sub>IH</sub>		Full		1.2	4.3	V
Input logic low	V <sub>IL</sub>		Full		0	0.5	V

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

SCDS189F-JANUARY 2005-REVISED MAY 2013

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## Electrical Characteristics for 1.8-V Supply<sup>(1)</sup>

 $V_{\star}$  = 1.65 V to 1.95 V,  $T_{A}$  = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CON	IDITIONS	TA	٧,	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V <sub>COM</sub> , V <sub>NC</sub> , V <sub>NO</sub>					0		V+	V
ON-state	r	$0 \le (V_{NC} \text{ or } V_{NO}) \le V_+,$	Switch ON,	25°C	1.65 V		5.50	8.00	Ω
resistance	r <sub>on</sub>	$I_{COM} = -32 \text{ mA},$	See Figure 19	Full	1.05 V			14.55	Ω
ON-state				25°C			0.30	1.00	
resistance match between channels	$\Delta r_{on}$	$V_{NC}$ or $V_{NO}$ = 1.5 V, $I_{COM}$ = -32 mA,	Switch ON, See Figure 19	Full	1.65 V			1.2	Ω
ON-state		$0 \leq (V_{NC} \text{ or } V_{NO}) \leq V_{+},$	Switch ON,	25°C			2.70	5.50	_
resistance flatness	r <sub>on(flat)</sub>	$I_{COM} = -32 \text{ mA},$	See Figure 19	Full	1.65 V			7.30	Ω
		$V_{NC}$ or $V_{NO} = 0.3 V$ ,		25°C		-0.25	0.03	0.25	
		$\label{eq:COM} \begin{array}{l} V_{COM} = 1.65 \text{V}, \\ \text{or} \\ V_{NC} \text{ or } V_{NO} = 1.65 \text{V}, \\ V_{COM} = 0.3 \text{ V}, \end{array}$	Switch OFF, See Figure 20	Full	1.95 V	-4.5		4.50	
NC, NO OFF leakage	I <sub>NC(OFF)</sub> ,	$V_{NC}$ or $V_{NO}$ = 1.95 V to 0		25°C		-0.40	0.01	0.40	μA
current	I <sub>NO(OFF)</sub>	V, V <sub>COM</sub> = 0 V to 1.95 V, or V <sub>NC</sub> or V <sub>NO</sub> = 0 V to 1.95 V, V, V <sub>COM</sub> = 1.95 V to 0 V,	Switch OFF, See Figure 20	Full	0 V	-6.5		6.50	
		$V_{COM} = 1.65 V,$		25°C		-0.40	0.02	0.40	
СОМ		$\label{eq:VNC} \begin{array}{l} V_{NC} \mbox{ or } V_{NO} = 0.3 \mbox{ V}, \\ \mbox{ or } \\ V_{COM} = 0.3 \mbox{ V}, \\ \mbox{ V}_{NC} \mbox{ or } V_{NO} = 1.65 \mbox{ V}, \end{array}$	Switch OFF, See Figure 20	Full	1.95 V	-0.90		0.90	
OFF leakage	I <sub>COM(OFF)</sub>	$V_{COM} = 0 V \text{ to } 1.95 V,$		25°C		-0.40	0.02	0.40	μA
current		$ \begin{array}{l} V_{NC} \mbox{ or } V_{NO} = 1.95 \mbox{ V to } 0 \\ V, \\ \mbox{ or } \\ V_{COM} = 1.95 \mbox{ V to } 0, \\ V_{NC} \mbox{ or } V_{NO} = 0 \mbox{ to } 1.95 \mbox{ V}, \end{array} $	Switch OFF, See Figure 20	Full	0 V	-4.50		4.50	
		$V_{NC}$ or $V_{NO} = 0.3 V$ ,		25°C		-2.0	0.02	2.00	
NC, NO ON leakage current	I <sub>NC(ON)</sub> , I <sub>NO(ON)</sub>	$\label{eq:COM} \begin{array}{l} V_{COM} = Open, \\ or \\ V_{NC} \mbox{ or } V_{NO} = 1.65 \mbox{ V}, \\ V_{COM} = Open, \end{array}$	Switch ON, See Figure 21	Full	1.95 V	-2.0	0.02	2.00	μA
		V <sub>COM</sub> = 0.3 V,		25°C		-4.50		4.50	
COM ON leakage current	I <sub>COM(ON)</sub>		Switch ON, See Figure 21	Full	1.95 V				μA
Digital Control	nputs (IN, EN)	(2)		·		-			
Input logic high	V <sub>IH</sub>	$V_I = V_+ \text{ or } GND$		Full	1.95 V	1.00		3.60	V
Input logic low	V <sub>IL</sub>			Full	1.95 V	0.00		0.40	V
Input leakage	I <sub>IH</sub> , I <sub>IL</sub>	$V_{I} = V_{+} \text{ or } 0$		25°C	1.95 V	-0.10	0.01	0.10	μA
current	יורי יוב			Full		-2.10		2.10	P., ,

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

(2) All unused digital inputs of the device must be held at V<sub>+</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



# SCDS189F - JANUARY 2005 - REVISED MAY 2013 Electrical Characteristics for 1.8-V Supply<sup>(1)</sup> (continued)

 $V_{+} = 1.65$  V to 1.95 V,  $T_{A} = -40^{\circ}$ C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST	CONDITIONS	T <sub>A</sub>	V.	MIN	TYP	MAX	UNIT
Dynamic									
				25°C	1.8 V		14.10	49.30	
Turn-on time	t <sub>ON</sub>		C <sub>L</sub> = 35 pF, See Figure 23	Full	1.65 V to 1.95 V		49.30	56.70	ns
				25°C	1.8 V		16.10	26.50	
Turn-off time	t <sub>OFF</sub>		C <sub>L</sub> = 35 pF, See Figure 23	Full	1.65 V to 1.95 V			31.20	ns
				25°C	1.8 V	5.30	18.40	58.00	
Break-before- make time	t <sub>BBM</sub>	$\label{eq:VNC} \begin{split} V_{\text{NC}} &= V_{\text{NO}} = V_{\text{+}}/2, \\ R_{\text{L}} &= 50 \ \Omega, \end{split}$	C <sub>L</sub> = 35 pF, See Figure 23	Full	1.65 V to 1.95 V			58.00	ns

SCDS189F - JANUARY 2005 - REVISED MAY 2013

TEXAS INSTRUMENTS

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## **TYPICAL PERFORMANCE**

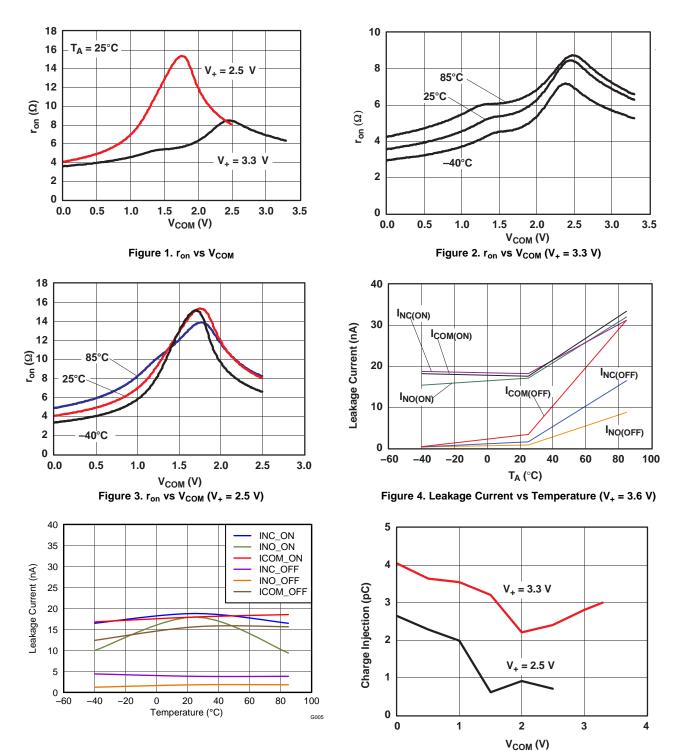
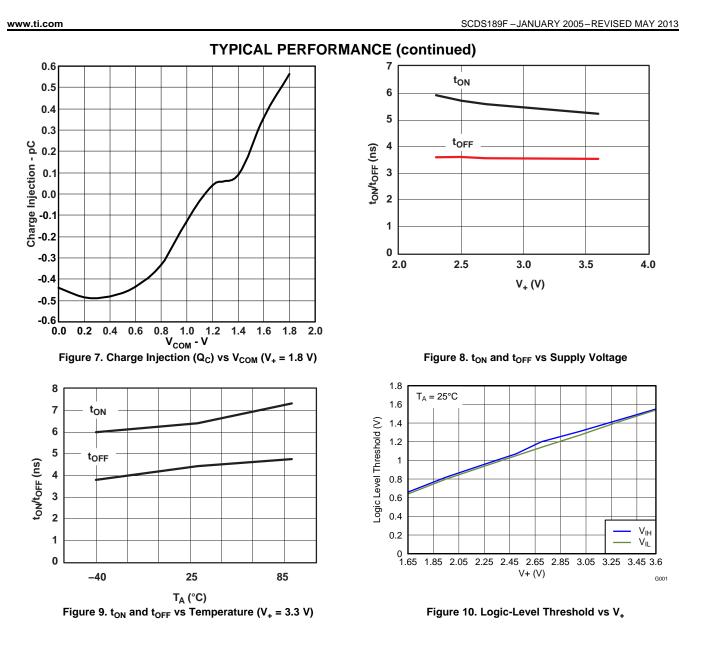


Figure 5. Leakage Current vs Temperature (V<sub>+</sub> = 1.8 V)

Figure 6. Charge Injection ( $Q_C$ ) vs  $V_{COM}$ 



## TS3A5018



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#### SCDS189F-JANUARY 2005-REVISED MAY 2013

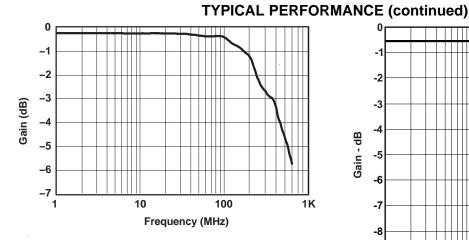
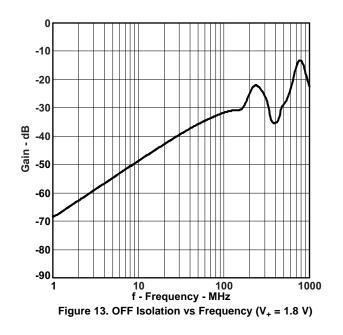
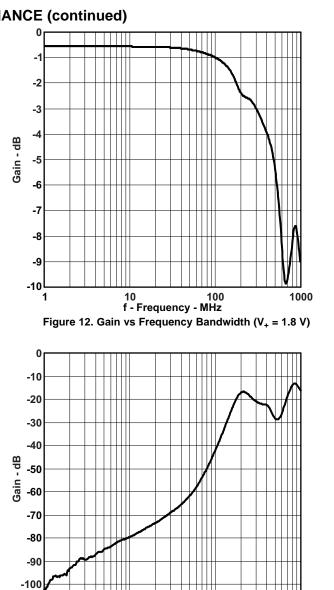


Figure 11. Gain vs Frequency Bandwidth (V<sub>+</sub> = 3.3 V)





-110 10 100 1000 f - Frequency - MHz

Figure 14. Crosstalk Adjacent vs Frequency (V<sub>+</sub> = 1.8 V)



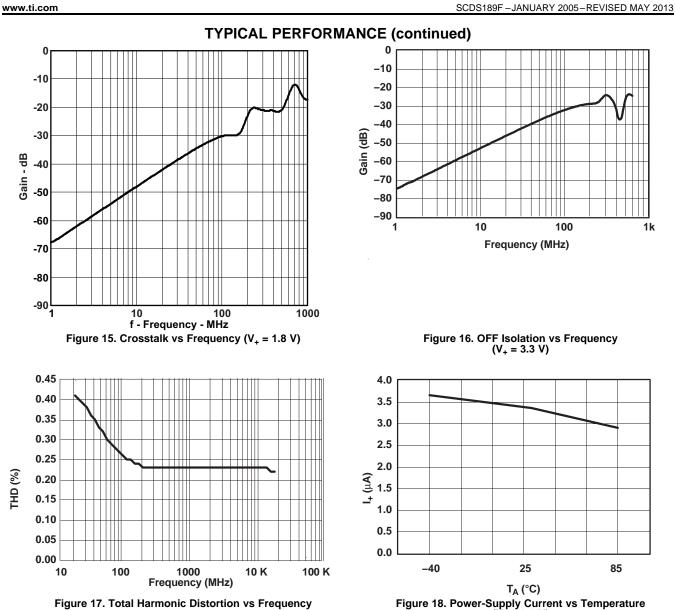


Figure 18. Power-Supply Current vs Temperature  $(V_+ = 3.3 V)$ 

PIN NO.	NAME	DESCRIPTION					
1	IN	Digital control pin to select between NC and NO					
2	NC1	Normally closed					
3	NO1	Normally open					
4	COM1	Common					
5	NC2	Normally closed					
6	NO2	Normally open					
7	COM2	Common					
8	GND	Digital ground					
9	COM3	Common					
10	NO3	Normally open					
11	NC3	Normally closed					

#### **PIN DESCRIPTION**

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## PIN DESCRIPTION (continued)

PIN NO.	NAME	DESCRIPTION
12	COM4	Common
13	NO4	Normally open
14	NC4	Normally closed
15	EN	Chip enable (active low)
16	V+	Power supply

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#### SCDS189F - JANUARY 2005 - REVISED MAY 2013

PARAMETER DESCRIPTION	
-----------------------	--

SYMBOL	DESCRIPTION
V <sub>COM</sub>	Voltage at COM
V <sub>NC</sub>	Voltage at NC
V <sub>NO</sub>	Voltage at NO
r <sub>on</sub>	Resistance between COM and NC or NO ports when the channel is ON
Δr <sub>on</sub>	Difference of r <sub>on</sub> between channels in a specific device
r <sub>on(flat)</sub>	Difference between the maximum and minimum value of ron in a channel over the specified range of conditions
I <sub>NC(OFF)</sub>	Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the OFF state
I <sub>NC(ON)</sub>	Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the ON state and the output (COM) open
I <sub>NO(OFF)</sub>	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the OFF state
I <sub>NO(ON)</sub>	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the ON state and the output (COM) open
I <sub>COM(OFF)</sub>	Leakage current measured at the COM port, with the corresponding channel (COM to NC or NO) in the OFF state
I <sub>COM(ON)</sub>	Leakage current measured at the COM port, with the corresponding channel (COM to NC or NO) in the ON state and the output (NC or NO) open
V <sub>IH</sub>	Minimum input voltage for logic high for the control input (IN, EN)
VIL	Maximum input voltage for logic low for the control input (IN, EN)
VI	Voltage at the control input (IN, EN)
I <sub>IH</sub> , I <sub>IL</sub>	Leakage current measured at the control input (IN, EN)
t <sub>ON</sub>	Turn-on time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output NC or NO) signal when the switch is turning ON.
t <sub>OFF</sub>	Turn-off time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (NC or NO) signal when the switch is turning OFF.
Q <sub>C</sub>	Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NC or NO) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, $Q_c = C_L \times \Delta V_{COM}$ , $C_L$ is the load capacitance and $\Delta V_{COM}$ is the change in analog output voltage.
C <sub>NC(OFF)</sub>	Capacitance at the NC port when the corresponding channel (NC to COM) is OFF
C <sub>NC(ON)</sub>	Capacitance at the NC port when the corresponding channel (NC to COM) is ON
C <sub>NO(OFF)</sub>	Capacitance at the NC port when the corresponding channel (NO to COM) is OFF
C <sub>NO(ON)</sub>	Capacitance at the NC port when the corresponding channel (NO to COM) is ON
C <sub>COM(OFF)</sub>	Capacitance at the COM port when the corresponding channel (COM to NC) is OFF
C <sub>COM(ON)</sub>	Capacitance at the COM port when the corresponding channel (COM to NC) is ON
CI	Capacitance of control input (IN, EN)
O <sub>ISO</sub>	OFF isolation of the switch is a measurement of OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NC to COM) in the OFF state.
X <sub>TALK</sub>	Crosstalk is a measurement of unwanted signal coupling from an ON channel to an OFF channel (NC1 to NO1). Adjacent crosstalk is a measure of unwanted signal coupling from an ON channel to an adjacent ON channel (NC1 to NC2) .This is measured in a specific frequency and in dB.
BW	Bandwidth of the switch. This is the frequency in which the gain of an ON channel is -3 dB below the DC gain.
THD	Total harmonic distortion describes the signal distortion caused by the analog switch. This is defined as the ratio of root mean square (RMS) value of the second, third, and higher harmonic to the absolute magnitude of the fundamental harmonic.
l+	Static power-supply current with the control (IN) pin at V <sub>+</sub> or GND

SCDS189F-JANUARY 2005-REVISED MAY 2013

## PARAMETER MEASUREMENT INFORMATION

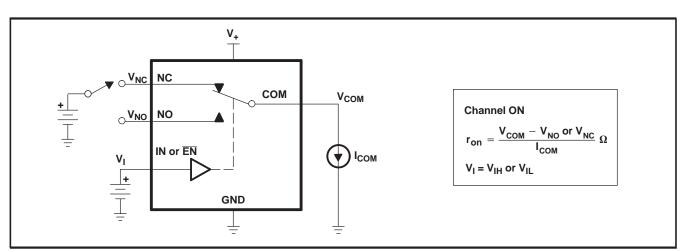


Figure 19. ON-State Resistance (ron)

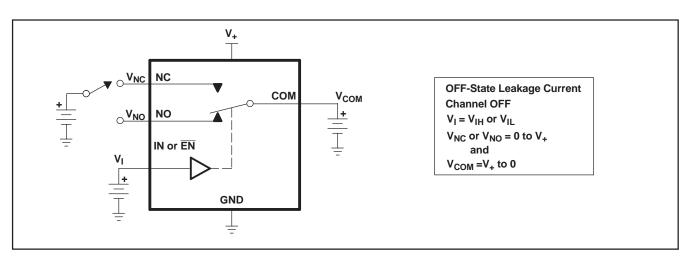
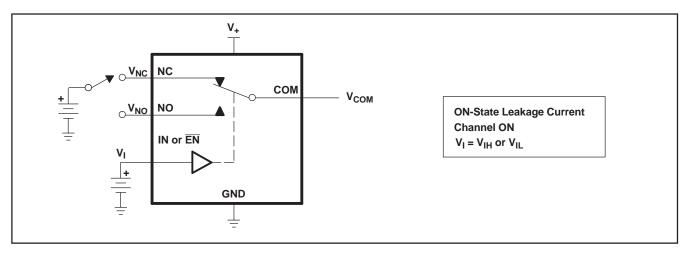
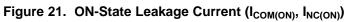


Figure 20. OFF-State Leakage Current (I<sub>COM(OFF)</sub>, I<sub>NC(OFF)</sub>, I<sub>NO(OFF)</sub>)







SCDS189F - JANUARY 2005 - REVISED MAY 2013



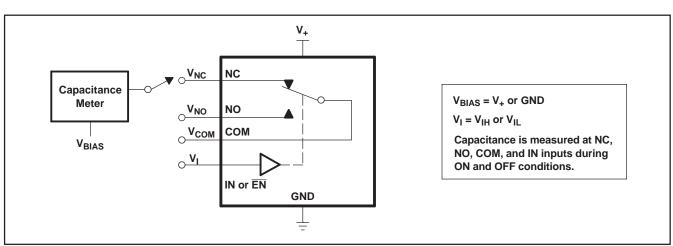
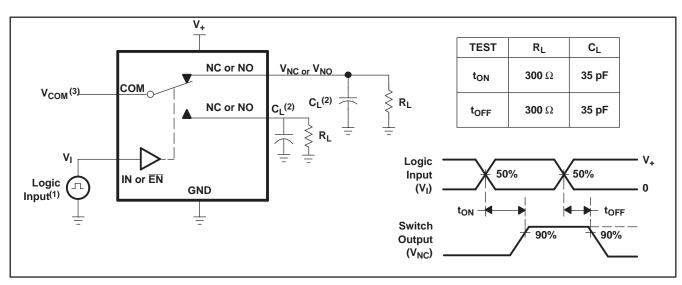


Figure 22. Capacitance (C<sub>I</sub>, C<sub>COM(OFF)</sub>, C<sub>COM(ON)</sub>, C<sub>NC(OFF)</sub>, C<sub>NC(ON)</sub>)



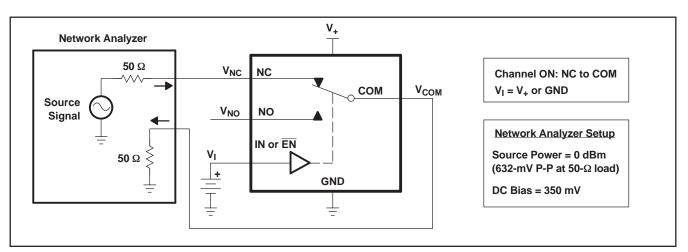
A. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>r</sub> < 5 ns, t<sub>f</sub> < 5 ns.

- B.  $C_L$  includes probe and jig capacitance.
- C. See Electrical Characteristics for  $V_{\mbox{COM}}.$

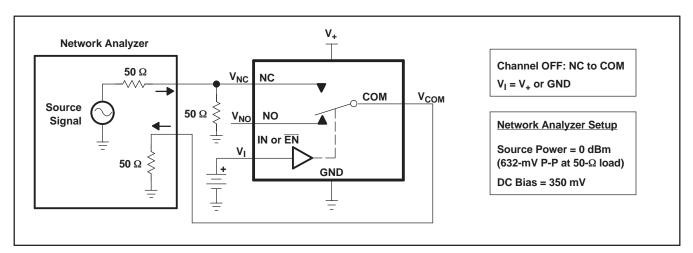
#### Figure 23. Turn-On $(t_{ON})$ and Turn-Off Time $(t_{OFF})$



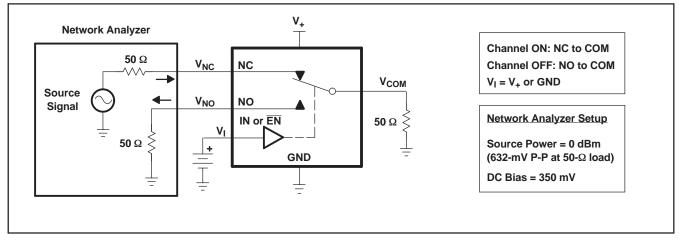
## PARAMETER MEASUREMENT INFORMATION (continued)



#### Figure 24. Bandwidth (BW)



## Figure 25. OFF Isolation (O<sub>ISO</sub>)



#### Figure 26. Crosstalk (X<sub>TALK</sub>)



## PARAMETER MEASUREMENT INFORMATION (continued)

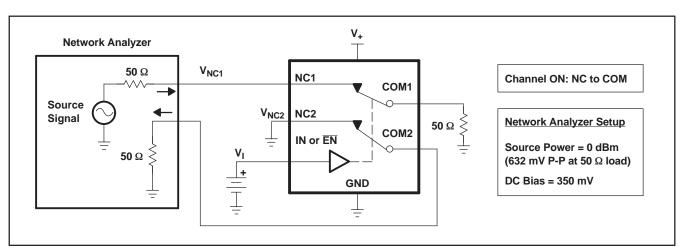
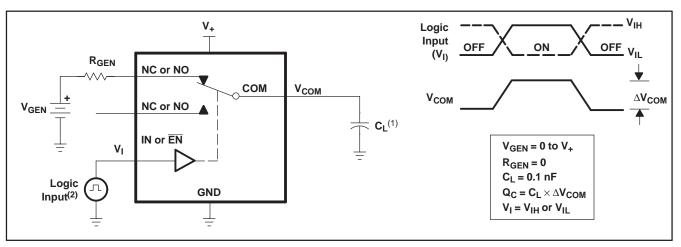


Figure 27. Crosstalk Adjacent

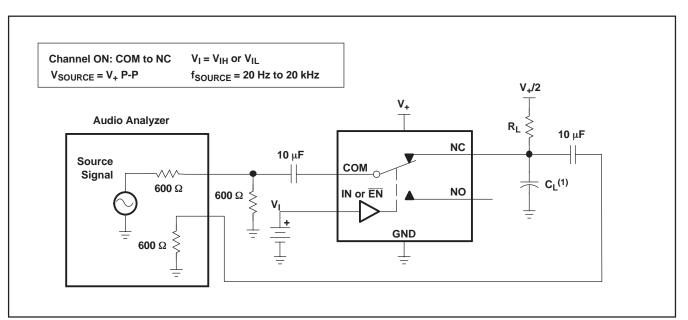


A. C<sub>L</sub> includes probe and jig capacitance.

B. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50 Ω, t<sub>r</sub> < 5 ns, t<sub>f</sub> < 5 ns.

Figure 28. Charge Injection (Q<sub>c</sub>)

SCDS189F-JANUARY 2005-REVISED MAY 2013



## PARAMETER MEASUREMENT INFORMATION (continued)

A. C<sub>L</sub> includes probe and jig capacitance.

Figure 29. Total Harmonic Distortion (THD)



SCDS189F - JANUARY 2005 - REVISED MAY 2013

## **REVISION HISTORY**

# Changes from Revision D (March 2010) to Revision E Page • Changed Single-Supply Operation in Features to 1.8-V to 3.6-V 1 • Changed V<sub>+</sub> range to 1.6 V to 2.0 V for 1.8-V Supply. 8 • Changed V<sub>+</sub> range to 1.6 V to 2.0 V for 1.8-V Supply. 9 Changes from Revision E (September 2011) to Revision F Page • Added Electrical Characteristics for 2.1-V Supply table to document. 7



20-May-2013

## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TS3A5018D	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TS3A5018	Samples
TS3A5018DBQR	ACTIVE	SSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	YA018	Samples
TS3A5018DBQRE4	ACTIVE	SSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	YA018	Samples
TS3A5018DBQRG4	ACTIVE	SSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	YA018	Samples
TS3A5018DE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TS3A5018	Samples
TS3A5018DG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TS3A5018	Samples
TS3A5018DGVR	ACTIVE	TVSOP	DGV	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	YA018	Samples
TS3A5018DGVRE4	ACTIVE	TVSOP	DGV	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	YA018	Samples
TS3A5018DGVRG4	ACTIVE	TVSOP	DGV	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	YA018	Samples
TS3A5018DR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TS3A5018	Samples
TS3A5018DRE4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TS3A5018	Samples
TS3A5018DRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TS3A5018	Samples
TS3A5018PW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	YA018	Samples
TS3A5018PWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	YA018	Samples
TS3A5018PWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	YA018	Samples
TS3A5018PWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	YA018	Samples
TS3A5018PWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	YA018	Samples



20-May-2013

Orderable Device	Status	Package Type	Package Drawing	Pins	-	Eco Plan	Lead/Ball Finish		Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)		(3)		(4/5)	
TS3A5018PWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	YA018	Samples
TS3A5018RGYR	ACTIVE	VQFN	RGY	16	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	YA018	Samples
TS3A5018RGYRG4	ACTIVE	VQFN	RGY	16	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	YA018	Samples
TS3A5018RSVR	ACTIVE	UQFN	RSV	16	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZUN	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(<sup>5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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# PACKAGE OPTION ADDENDUM

20-May-2013

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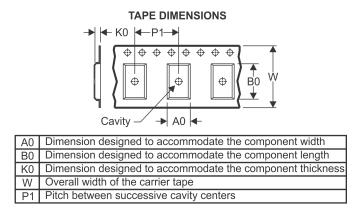
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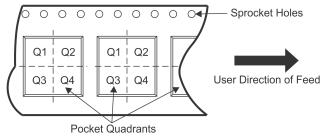
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#### TAPE AND REEL INFORMATION





# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



All dimensions are nominal	_							-		-		-
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS3A5018DGVR	TVSOP	DGV	16	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
TS3A5018DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TS3A5018PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TS3A5018RGYR	VQFN	RGY	16	3000	330.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1
TS3A5018RSVR	UQFN	RSV	16	3000	180.0	12.4	2.1	2.9	0.75	4.0	12.0	Q1
TS3A5018RSVR	UQFN	RSV	16	3000	330.0	12.4	2.1	2.9	0.75	4.0	12.0	Q1
TS3A5018RSVR	UQFN	RSV	16	3000	177.8	12.4	2.0	2.8	0.7	4.0	12.0	Q1

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# PACKAGE MATERIALS INFORMATION

13-May-2013



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS3A5018DGVR	TVSOP	DGV	16	2000	367.0	367.0	35.0
TS3A5018DR	SOIC	D	16	2500	333.2	345.9	28.6
TS3A5018PWR	TSSOP	PW	16	2000	367.0	367.0	35.0
TS3A5018RGYR	VQFN	RGY	16	3000	367.0	367.0	35.0
TS3A5018RSVR	UQFN	RSV	16	3000	203.0	203.0	35.0
TS3A5018RSVR	UQFN	RSV	16	3000	180.0	180.0	30.0
TS3A5018RSVR	UQFN	RSV	16	3000	202.0	201.0	28.0

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.  $\beta$ . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



# PW (R-PDSO-G16)

# PLASTIC SMALL OUTLINE



- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



# **MECHANICAL DATA**



- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- Ε. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Æ Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated.
- The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



# RGY (R-PVQFN-N16)

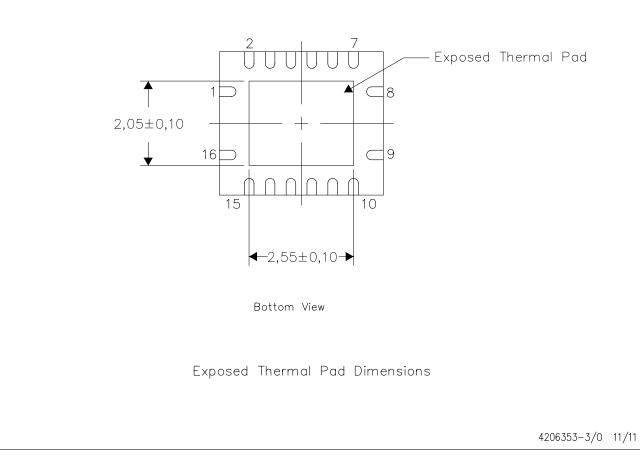
## PLASTIC QUAD FLATPACK NO-LEAD

#### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

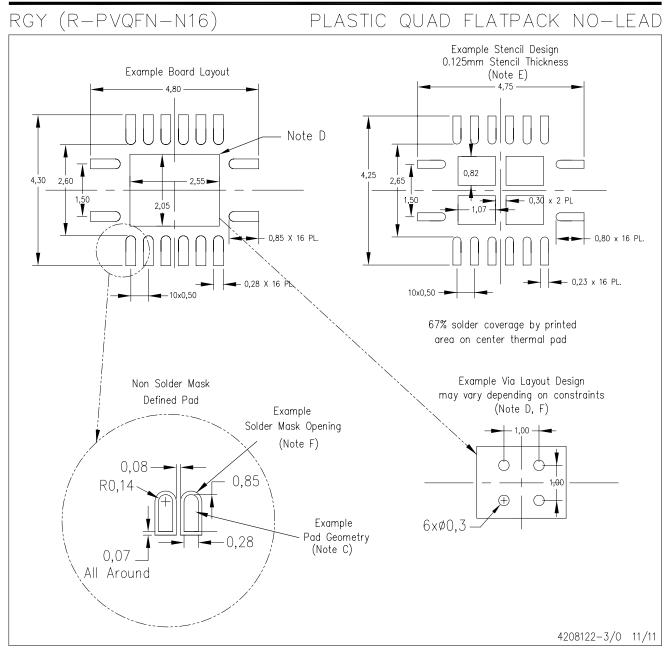
For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



#### NOTE: All linear dimensions are in millimeters





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.

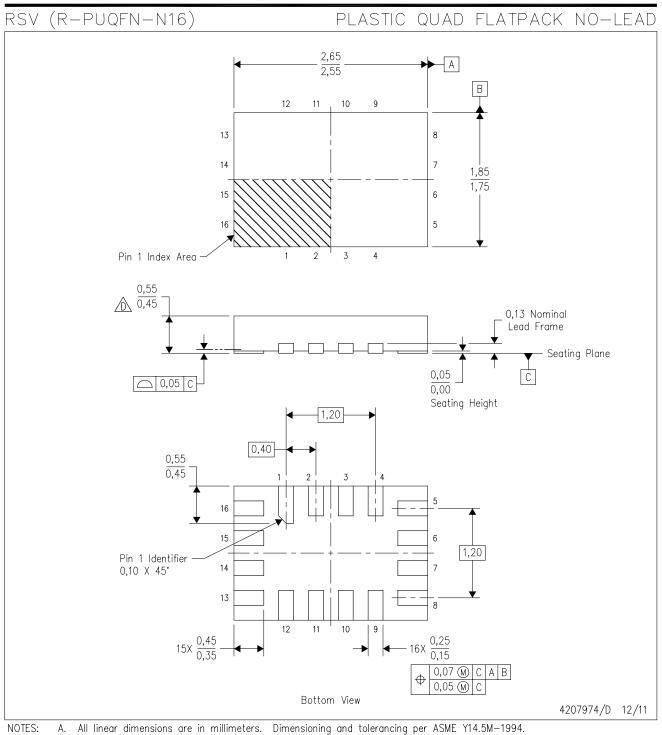
D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>.

E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.

F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



# **MECHANICAL DATA**



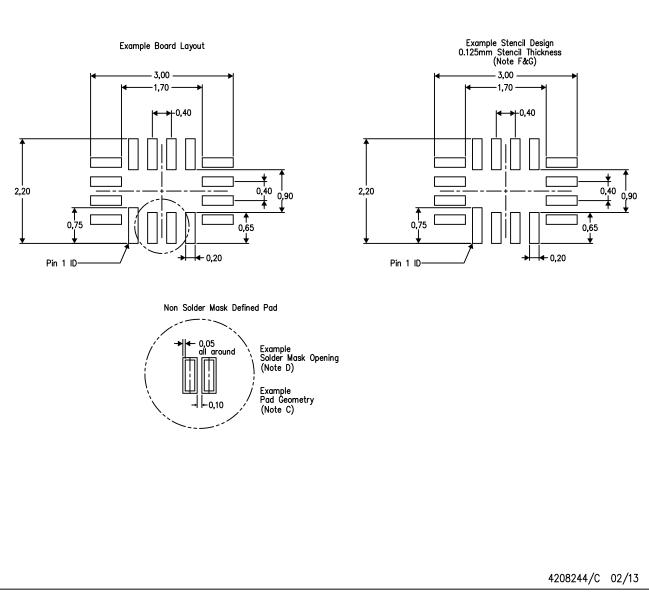
- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.

ightarrow This package complies to JEDEC MO-288 variation UFHE, except minimum package thickness.



## RSV (R-PUQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD



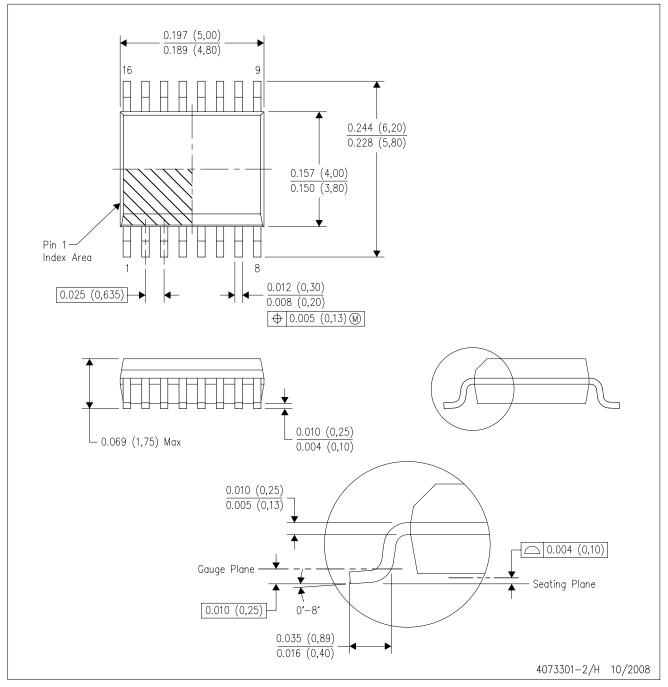
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over-print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.



DBQ (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



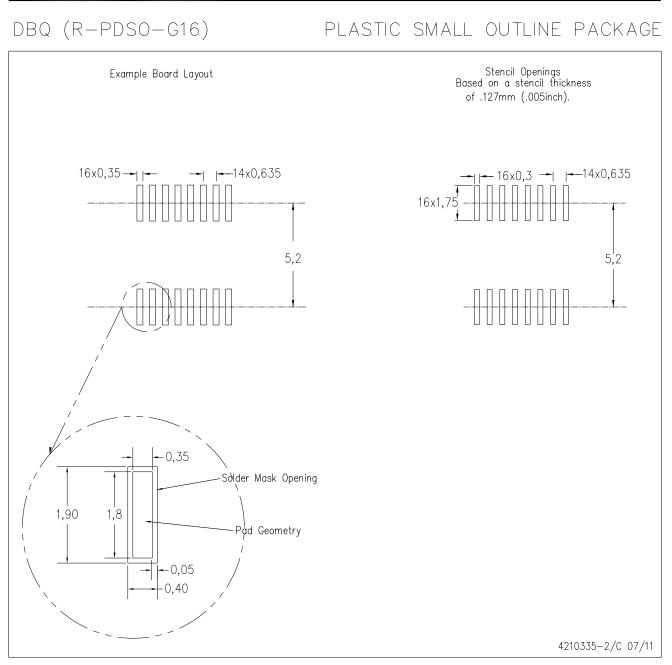
NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.

D. Falls within JEDEC MO-137 variation AB.





NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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